Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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HAT2165N

Silicon N Channel Power MOS FET Power Switching

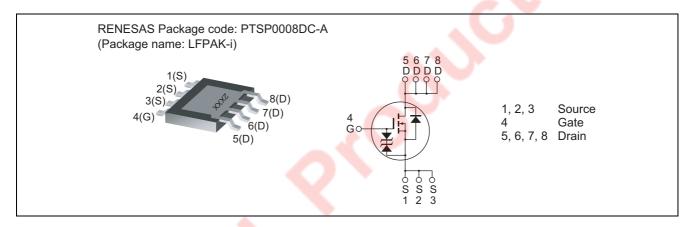
REJ03G1680-0300 Rev.3.00 May 27, 2008

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance

 $R_{DS(on)}$ = 2.8 m Ω typ. (at V_{GS} = 10 V)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	30	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	55	Α
Drain peak current	I _{D(pulse)} Note1	220	Α
Body-drain diode reverse drain current	I _{DR}	55	Α
Avalanche current	I _{AP} Note 2	30	Α
Avalanche energy	E _{AR} Note 2	90	mJ
Channel dissipation	Pch Note3	30	W
Channel to case thermal resistance	θch-C	4.17	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. $PW \le 10 \infty$, duty cycle $\le 1\%$

2. Value at Tch = 25°C, Rg \geq 50 Ω

3. $Tc = 25^{\circ}C$

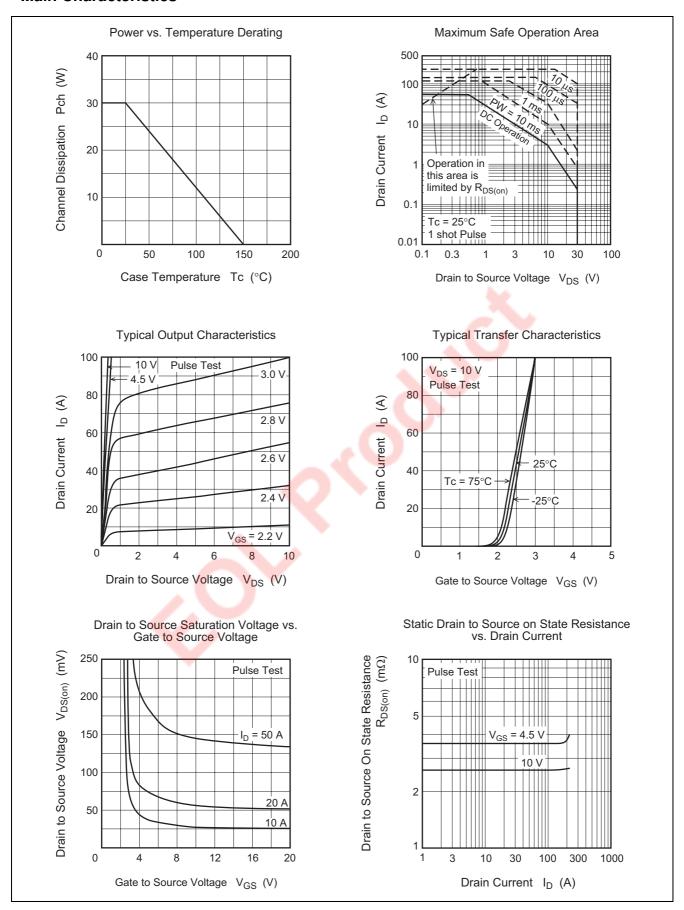
Electrical Characteristics

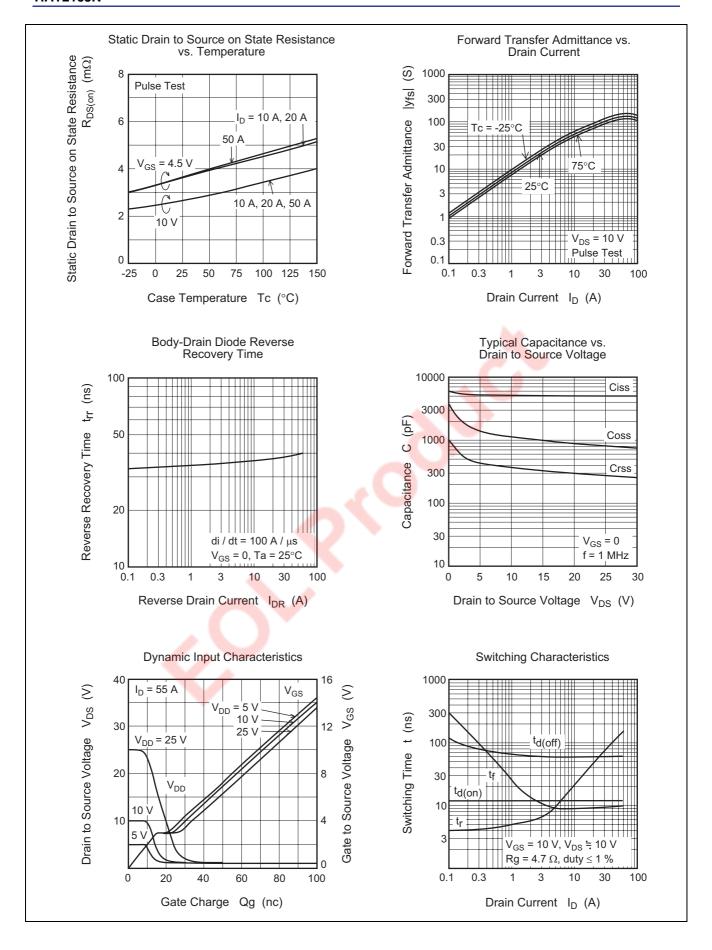
 $(Ta = 25^{\circ}C)$

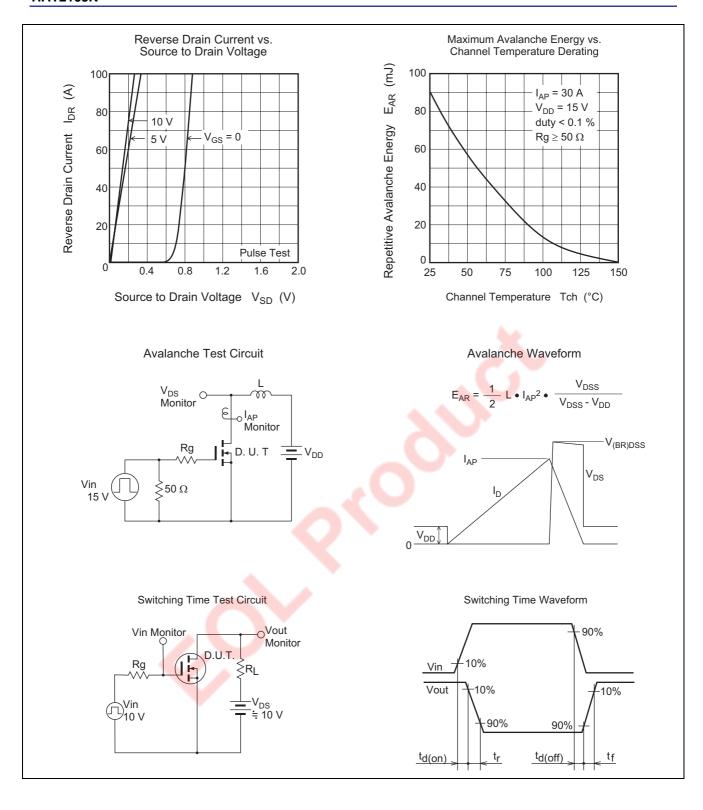
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Drain to source breakdown voltage	V _{(BR)DSS}	30	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$	
Gate to source breakdown voltage	V _{(BR)GSS}	±20	_	_	V	$I_G=\pm 100 $	
Gate to source leak current	I _{GSS}	_	_	±10	∝A	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$	
Zero gate voltage drain current	I _{DSS}	_	_	1	∝A	$V_{DS} = 30 \text{ V}, V_{GS} = 0$	
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	_	2.5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$	
Static drain to source on state	R _{DS(on)}	_	2.8	3.6	mΩ	$I_D = 27.5 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$	
resistance	R _{DS(on)}	_	3.7	5.6	mΩ	$I_D = 27.5 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note4}}$	
Forward transfer admittance	y _{fs}	60	100	1	S	$I_D = 27.5 \text{ A}, V_{DS} = 10 \text{ V}^{Note4}$	
Input capacitance	Ciss	_	5180	1	pF	V _{DS} = 10 V	
Output capacitance	Coss	_	1200		pF	$V_{GS} = 0$	
Reverse transfer capacitance	Crss	_	380		pF	f = 1 MHz	
Gate resistance	Rg	_	0.5		Ω		
Total gate charge	Qg	_	33	_	nc	$V_{DD} = 10 \text{ V}$	
Gate to source charge	Qgs	_	15	_	nc	$V_{GS} = 4.5 \text{ V}$	
Gate to drain charge	Qgd	_	7.1	_	nc	$I_D = 55 A$	
Turn-on delay time	t _{d(on)}	_	13		ns	$V_{GS} = 10 \text{ V}, I_D = 27.5 \text{ A}$	
Rise time	t _r	_	65		ns	V _{DD} ≅ 10 V	
Turn-off delay time	$t_{d(off)}$	_	60	_	ns	$R_L = 0.36 \Omega$	
Fall time	t _f	_	9.5	-	ns	$Rg = 4.7 \Omega$	
Body-drain diode forward voltage	V_{DF}		0.81	1.06	٧	$I_F = 55 \text{ A}, V_{GS} = 0^{\text{Note4}}$	
Body-drain diode reverse recovery	t _{rr}	_	40		ns	$I_F = 55 \text{ A}, V_{GS} = 0$	
time						di _F / dt = 100 A/ ∞s	

Notes: 4. Pulse test

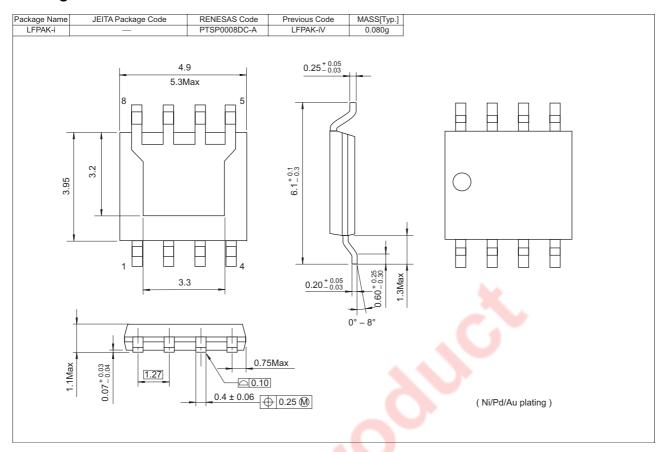
Main Characteristics







Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
HAT2165N-EL-E	2500 pcs	Taping

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